

A New Scheme of High-Energy THz Source Using Nonlinear Crystal with Attached Multistep Phase Mask

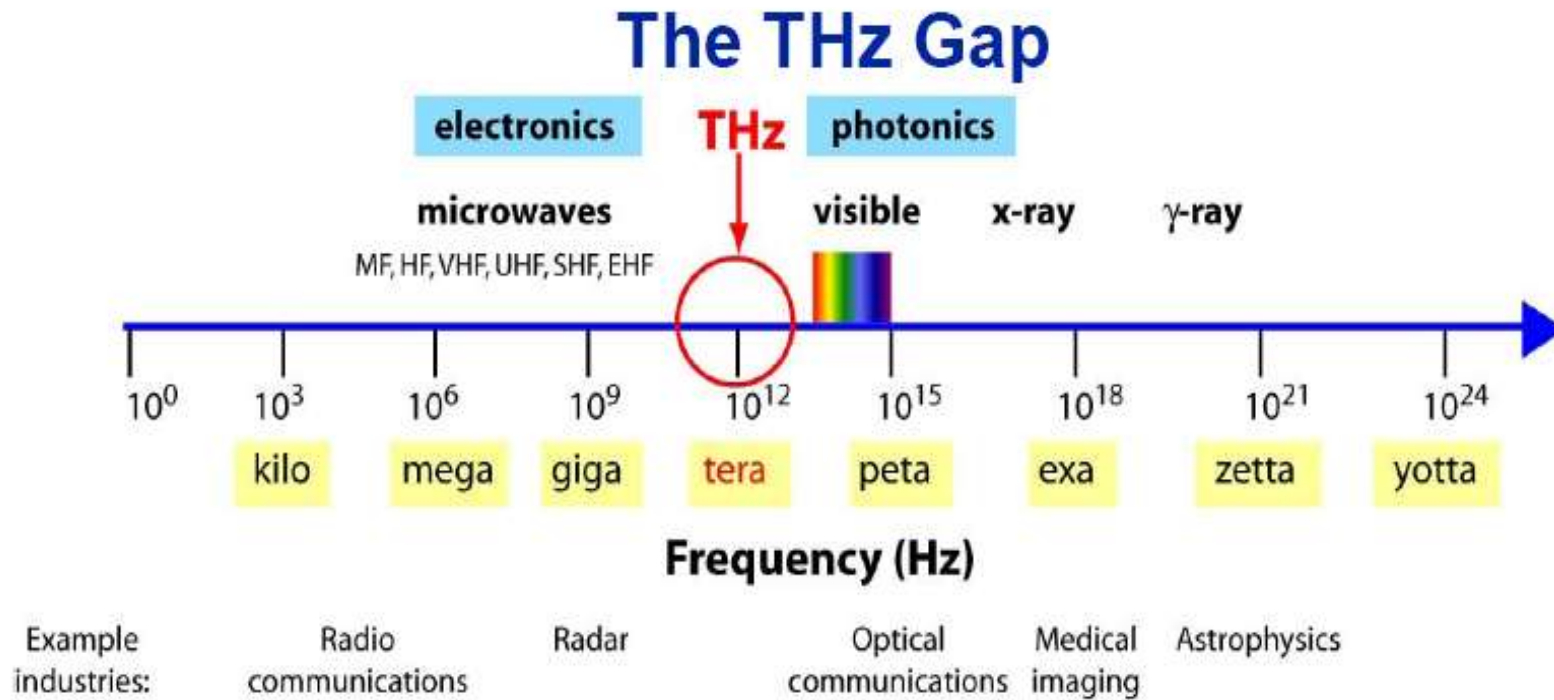
*Yu. H. Avetisyan, A. H. Makaryan, V. R. Tadevosyan
Yerevan State University, Armenia*

OUTLINE

1. Introduction.
2. Optical rectification in mask covered NLO crystals.
3. Masks design for LiNbO_3 and ZnTe crystals.
4. Results and discussions.
4. Conclusions.



THz region



$$1 \text{ THz} \sim 1 \text{ ps} \sim 300 \mu\text{m} \sim 33 \text{ cm}^{-1} \sim 4.1 \text{ meV} \sim 47.6 \text{ K}$$

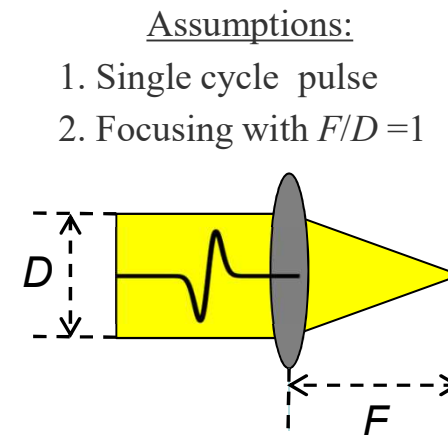
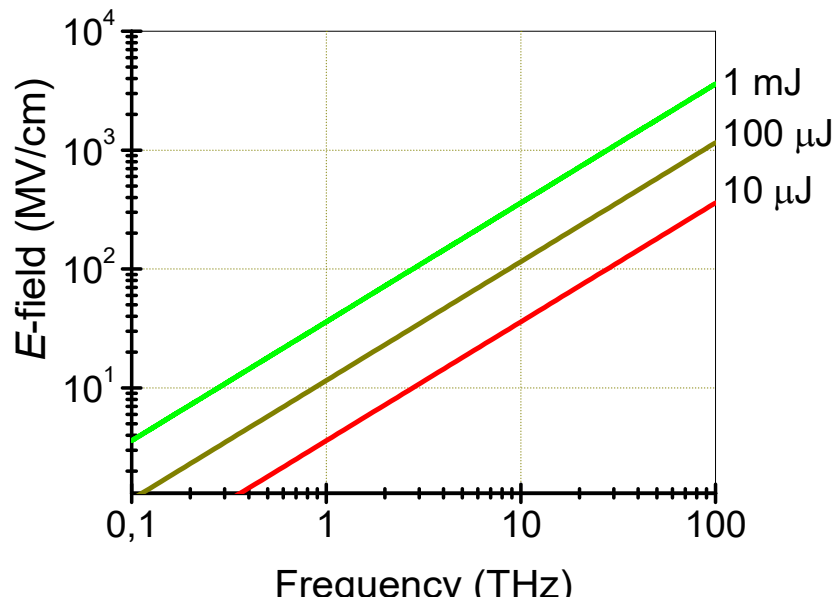


Attractive features of THz waves

- **Signature:** Rotation and vibrational modes of many molecules lie within the THz spectral range.
- **Safely:** THz-ray has low photon energy ($\sim 10^6$ times weaker than a X-ray photon) and will not cause harmful photoionization in the biological tissues.
- **Transparency and resolution:** Most materials such as plastic, paper, cardboard, textiles and ceramics are transparent to THz radiation. In contrast to microwave, the shorter wavelength improves the resolution in imaging applications.
- **Wireless communication:** Extremely wide bandwidth (up to several THz) leads to potential speed of several terabits-per-second.

Applications of strong THz-field in research

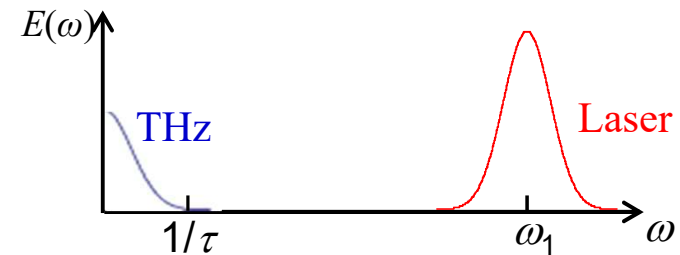
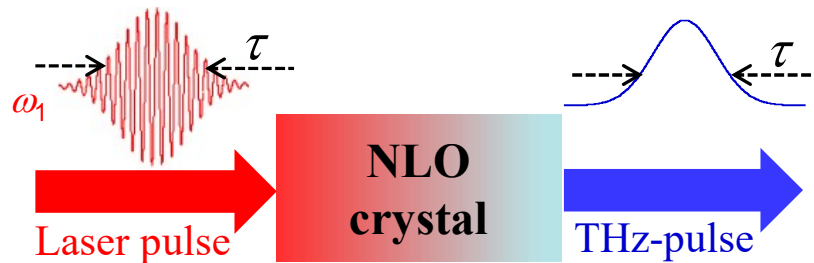
- Nonlinear optics investigation at THz frequencies.
- THz time-domain nonlinear spectroscopy.
- Acceleration of charged particles & THz driven undulator for X-ray. (AXSIS project under development in DESY).
- Control and measurements of electron bunch.



Optical rectification in NLO crystal

$$P(t) = \varepsilon_0 (\alpha E + 2dE^2 + \gamma E^3 + \dots)$$

$$E = \text{Re}(E_0(t)e^{i\omega_0 t})$$



$$\vec{k}_{THz} = \vec{k}_g$$

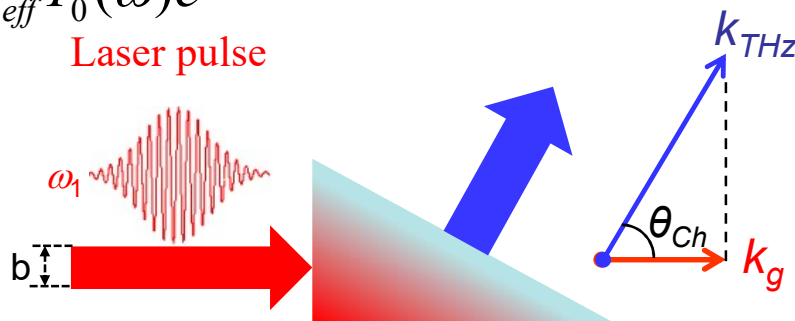
$\bullet \longrightarrow k_{THz} = \omega / v_{THz}$
 $\bullet \longrightarrow k_g = \omega / u_g$

$$v_{THz} = c/n_{THz} \Rightarrow n_{THz} = n_g$$

$$u_g = c/n_g$$

$$P_{NL}(t) \sim d_{eff} I_0(\omega) e^{-ik_g z}$$

Laser pulse

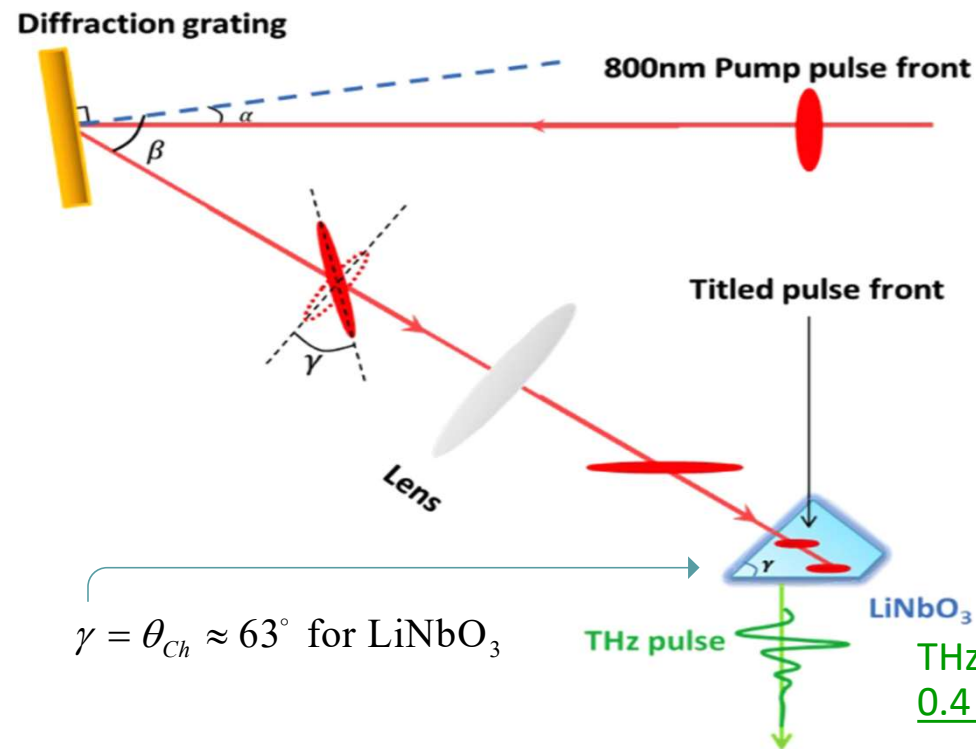


$$\cos \theta_{Ch} = v_{THz} / u_g = n_g / n_{THz}$$

$$b \ll \frac{\lambda_{THz}}{2n_{THz} \sin \theta_{Ch}} \approx 33 \mu m$$

Tilted pulse-front pumping

The use of large-aperture optical beam for PM THz generation is possible using TFPF technique [1].



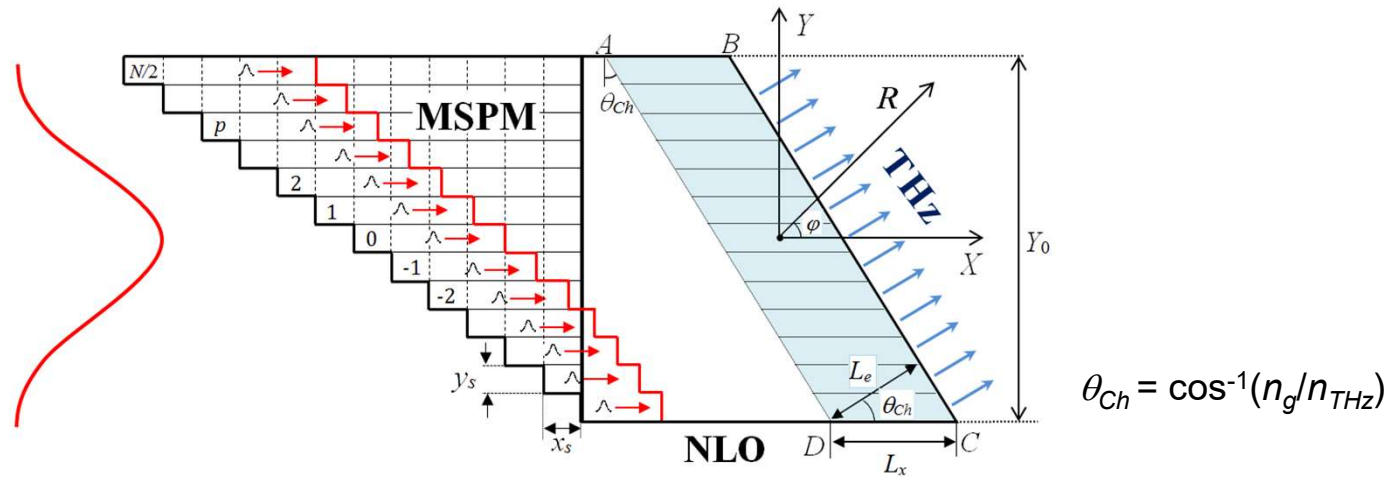
J. Hebling, et al.
Opt. Lett. **10**, 1161, (2002).

J. Fülöp, et al. Opt. Exp.
22, 20155, (2014).

THz pulses with energy
0.4 mJ were obtained [2].

Further increase is challenging because of serious limitations:
imaging errors in crystal and temporal broadening of the pump pulse.

THz in NLO crystal with MSPM



$$E_p(\nu) = A d_{eff} \nu I_p(\nu) y_s \text{sinc}\left(\frac{\pi y_s}{2l_c(\nu)}\right), \quad l_c(\nu) = \frac{c}{2\nu n_{THz} \sin \theta_{Ch}}, \quad I_p(\nu) = \sqrt{\pi} \tau_L I_0 e^{-\pi^2 \nu^2 \tau_L^2} e^{-i2\pi\nu\tau}$$

$= 2/\pi$ at $y_s = l_c(1\text{THz}) \equiv y_0$
 $\tau = x_s (n_{gm} - 1)/c$

$$y_0 = \frac{150}{\sqrt{n_{THz}^2 - n_g^2}} \quad [\mu\text{m}],$$

$$x_0 = \frac{150}{n_{gm} - 1} \quad [\mu\text{m}].$$

THz-pulse in the far-field

$$E_{THz}(\omega, \varphi) = \sum_{p=-N/2}^{N/2} E_{zp}(\omega, \varphi) \approx \frac{Ae^{-ikR} d_{eff} y_0 r_y I_0 e^{-\frac{\omega^2 \tau_L^2}{4}}}{R_0} L_x \text{sinc}\left(\frac{\Delta k L_x}{2}\right) \Phi(\omega, \varphi),$$

with $\Phi(\omega, \varphi) = \sum_{p=-N/2}^{N/2} \exp\left\{ip\left[\frac{\omega}{c} n_T(\omega) y_0 \sin \varphi - \Delta k y_0 \tan \theta_{Ch} - x_0 (n_{gm} - 1)\right]\right\} \exp\left[-2\left(py_0 / r_y\right)^2\right]$.

NLO	λ_{pump} [μm]	d_{eff} [pm/V]	x_0 [μm]	y_0 [μm]	R_{el} [mm]	N	r_y [mm]	I_{av} [GW/cm ²]	α (1 THz) [cm ⁻¹]
ZnTe	1.7	68.5	200	98.0	31	30	1.5	13.5 [1]	2.2
LN	1.03	168	200	33.7	6	30	0.5	20 [2, 3]	13

[1]. Gy. Polónyi et al. Opt. Express **24**, 23872 (2016).

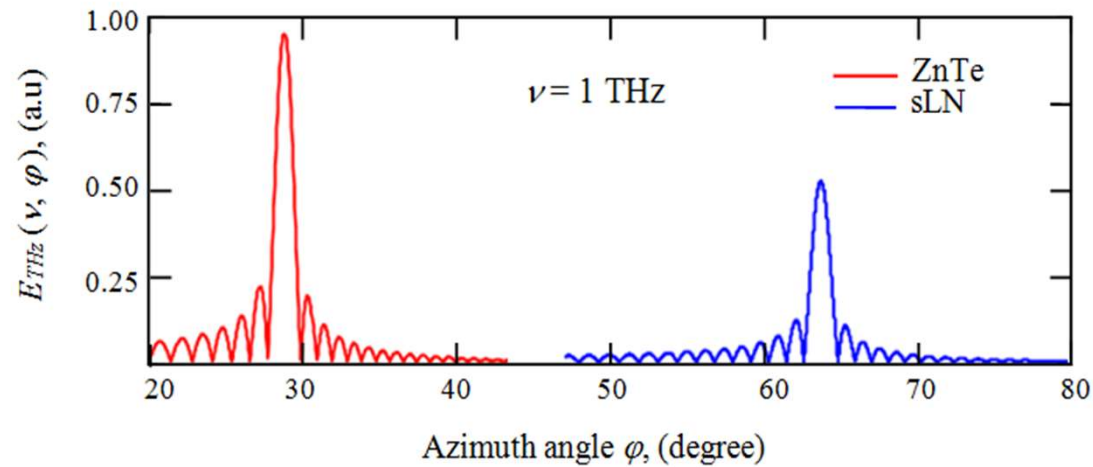
[2]. M.C. Hoffmann, K.-L. Yeh, J. Hebling, and K. A. Nelson, Opt. Express **15**, 11706 (2007).

[3]. K. Ravi, W. R. Huang, S. Carbajo, X. Wu, and F. X. Kärtner, Opt. Express **22**, 20239 (2014).



THz radiation pattern

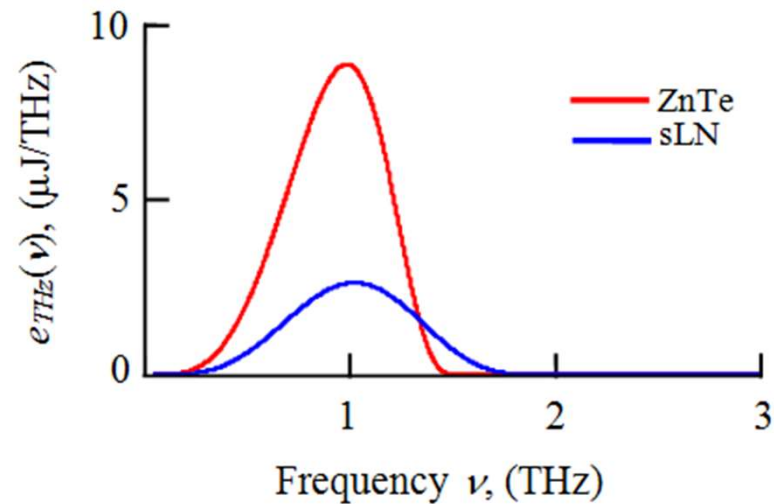
THz electric field in the frequency domain at 1 THz.



$\varphi_m = 28.7^\circ$ and 63.6° for ZnTe and LN
 $\Delta\varphi \approx 1^\circ$ for both ZnTe and LN crystals

THz-pulse energy spectral density

$$\varepsilon_{THz}(\omega) = \frac{n_{THz}}{4\pi W} |E_{THz}(\omega, \theta_{Ch})|^2 R^2 \Delta\varphi \Delta\theta_z,$$



$\Theta_{THz} = 10.5 \mu\text{J}$ and $4.1 \mu\text{J}$ for ZnTe and LN
 $\varepsilon_L = 0,9 \text{ mJ}$ and $0,5 \text{ mJ}$ for ZnTe and LN

Conclusions

- A new scheme of high-energy THz pulse generation in ZnTe and LN crystals based on using MSPM is proposed and analyzed.
- The design of MSPM is performed.
- The THz field is analytically calculated using radiating antenna model.
- The ZnTe crystal allows obtaining higher THz-pulse energy than that of LN crystal, especially when long-wavelength pump sources are used.

Thank you

